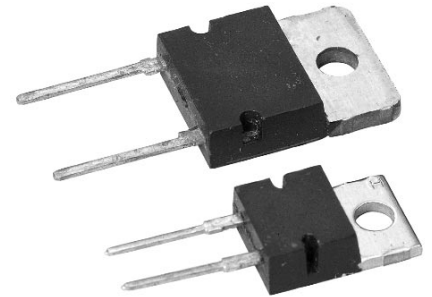


|   |   |                  |                  |
|---|---|------------------|------------------|
| V <sub>RSM</sub><br>V <sub>RRM</sub><br><br>V | I <sub>FRMS</sub> (maximum values for continuous operation)   |                  |                  |
|   | 30 A  | 47 A             | 72 A             |
|   | I <sub>FAV</sub> (sin. 180; T <sub>case</sub> = 85 °C; 50 Hz) |                  |                  |
|   | 20 A  | 31 A             | 48 A             |
| 1000  | <b>SKR 20F10</b>  | <b>SKR 31F10</b> | <b>SKR 48F10</b> |
| 1200  | <b>SKR 20F12</b>  | <b>SKR 31F12</b> | <b>SKR 48F12</b> |

**Fast Recovery Rectifier Diodes <sup>1)</sup>**

**SKR 20 F**  
**SKR 31 F**  
**SKR 48 F**



| Symbol            | Conditions  | SKR20F            | SKR31F            | SKR48F           | Units            |         |
|-------------------|---|-------------------|-------------------|------------------|------------------|---------|
| I <sub>FAV</sub>  | sin. 180; T <sub>case</sub> = 85 °C                         | 20                | 31                | 48               | A                |         |
| I <sub>FSM</sub>  | T <sub>vj</sub> = 25 °C; 10 ms                              | 150               | 320               | 500              | A                |         |
|                   | T <sub>vj</sub> = 150 °C; 10 ms                             | 140               | 300               | 450              | A                |         |
| i <sup>2</sup> t  | T <sub>vj</sub> = 25 °C; 8,3 ... 10 ms                      | 110               | 510               | 1250             | A <sup>2</sup> s |         |
|                   | T <sub>vj</sub> = 150 °C; 8,3 ... 10 ms                     | 100               | 450               | 1000             | A <sup>2</sup> s |         |
| I <sub>RRM</sub>  | T <sub>vj</sub> = 25 °C                                     | 12 <sup>2)</sup>  | 19 <sup>3)</sup>  | 23 <sup>4)</sup> | A                |         |
|                   | T <sub>vj</sub> = 125 °C                                    | 16 <sup>2)</sup>  | 25 <sup>3)</sup>  | 35 <sup>4)</sup> | A                |         |
| Q <sub>rr</sub>   | T <sub>vj</sub> = 25 °C typ.                                | 1,5 <sup>2)</sup> | 2 <sup>3)</sup>   | 3 <sup>4)</sup>  | μC               |         |
|                   | T <sub>vj</sub> = 125 °C typ.                               | 2,7 <sup>2)</sup> | 4,5 <sup>3)</sup> | 8 <sup>4)</sup>  | μC               |         |
| t <sub>rr</sub>   | T <sub>vj</sub> = 25 °C typ.                                | 80 <sup>2)</sup>  | 100 <sup>3)</sup> | 80 <sup>4)</sup> | ns               |         |
| I <sub>R</sub>    | T <sub>vj</sub> = 25 °C; V <sub>R</sub> = V <sub>RRM</sub>  | 0,1               | 0,1               | 0,2              | mA               |         |
|                   | T <sub>vj</sub> = 125 °C; V <sub>R</sub> = V <sub>RRM</sub> | 2                 | 4                 | 4                | mA               |         |
| V <sub>F</sub>    | T <sub>vj</sub> = 25 °C; max (I <sub>F</sub> = . . . A)     | 2,5<br>(15)       | 2,35<br>(25)      | 2,5<br>(50)      | V<br>A           |         |
| V <sub>(TO)</sub> | T <sub>vj</sub> = 150 °C                                    | 1,2               | 1,2               | 1,2              | V                |         |
| r <sub>T</sub>    | T <sub>vj</sub> = 150 °C                                    | 70                | 44                | 22               | mΩ               |         |
| R <sub>thjc</sub> |   | 0,70              | 0,45              | 0,35             | °C/W             |         |
| R <sub>thch</sub> |   | 0,30              | 0,30              | 0,25             | °C/W             |         |
| T <sub>vj</sub>   |   | - 40 ... 150      |                   |                  | °C               |         |
| T <sub>stg</sub>  |   | - 40 ... 150      |                   |                  | °C               |         |
| M <sub>1</sub>    | to heatsink   | SI Units          | 0,55...0,8        | 0,7...1          | 0,7...1          | Nm      |
|                   |   | US units          | 4,8 ...7,1        | 6,2...8,8        | 6,2...8,8        | lb. in. |
| w                 | approx.   | 2                 | 5                 | 5                | g                |         |
| Case              |   | E 39              | E 40              | E 40             |                  |         |

**Features**

- Very short recovery times
- Soft recovery under all conditions
- Up to 1200 V reverse voltage
- Epoxy meets UL 94V-0 flammability classification

**Typical Applications**

- Inverse diode for power transistors
- Inverter, UPS
- Snubber and clamping diode

<sup>1)</sup> CAL (controlled axial lifetime) technology, patent No. DE 43 10 44

<sup>2)</sup> I<sub>F</sub> = 15 A, di/dt = 400 A/μs, V<sub>R</sub> = 600 V

<sup>3)</sup> I<sub>F</sub> = 25 A, di/dt = 500 A/μs, V<sub>R</sub> = 600 V

<sup>4)</sup> I<sub>F</sub> = 50 A, di/dt = 800 A/μs, V<sub>R</sub> = 600 V

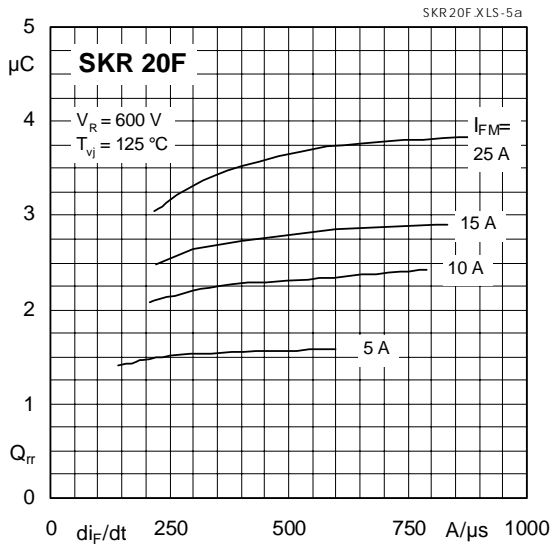


Fig. 5 a Typ. recovered charge

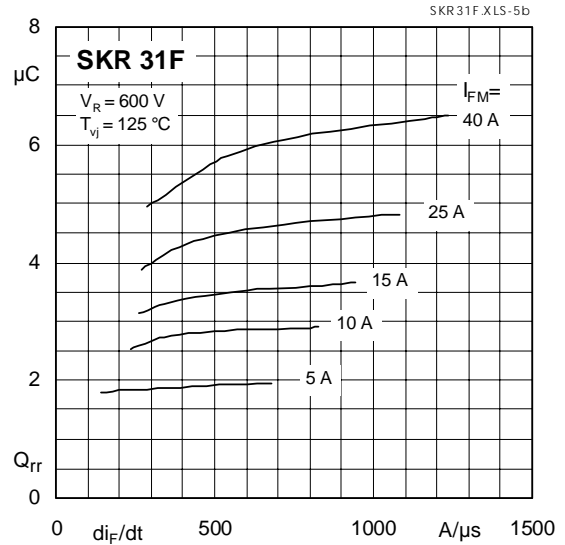


Fig. 5 b Typ. recovered charge

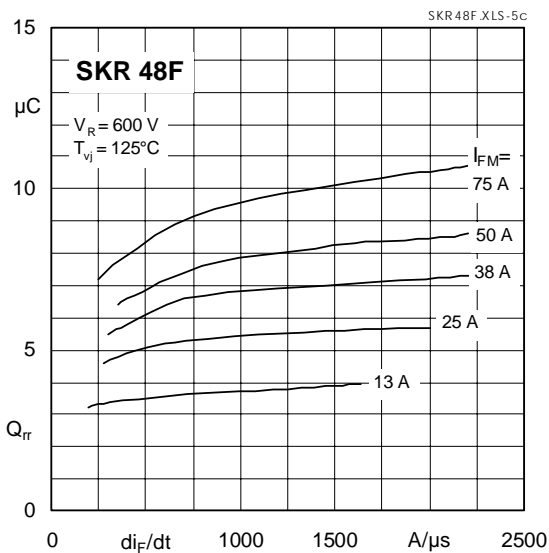


Fig. 5 c Typ. recovered charge

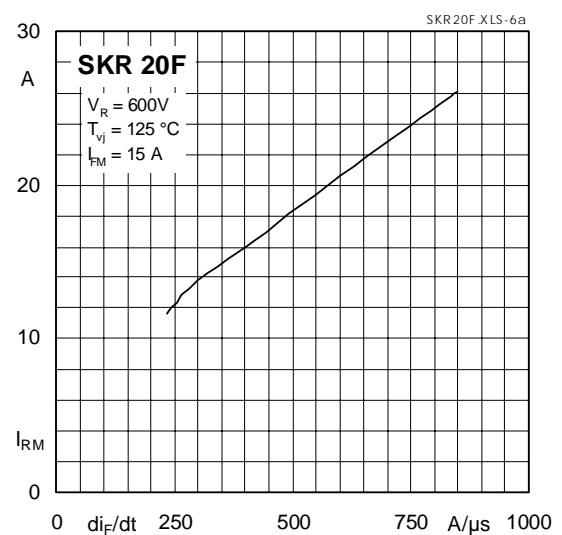


Fig. 6 a Typ. peak reverse recovery current

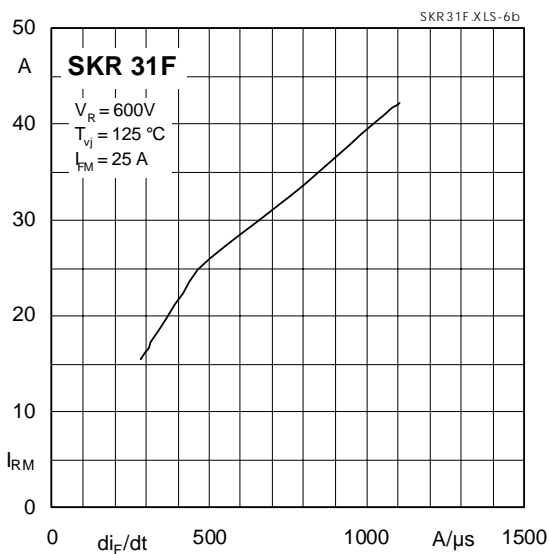


Fig. 6 b Typ. peak reverse recovery current

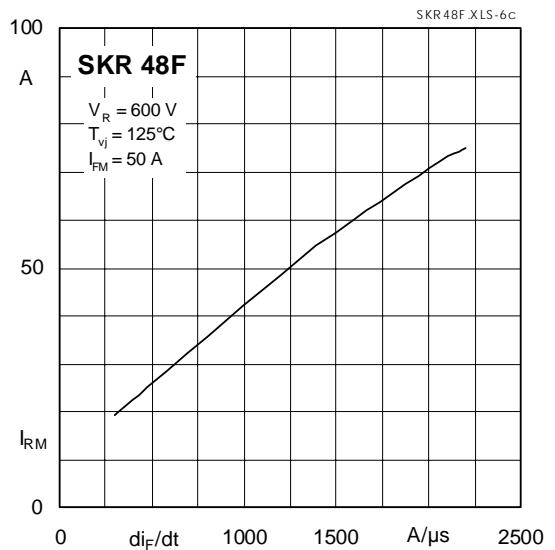


Fig. 6 c Typ. peak reverse recovery current

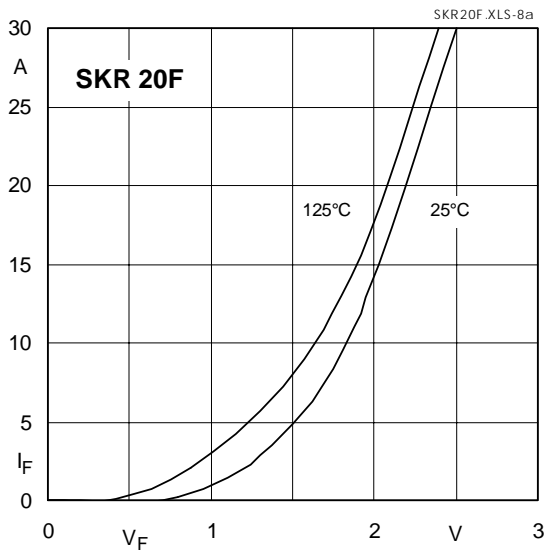


Fig. 8 a Typ. forward characteristics

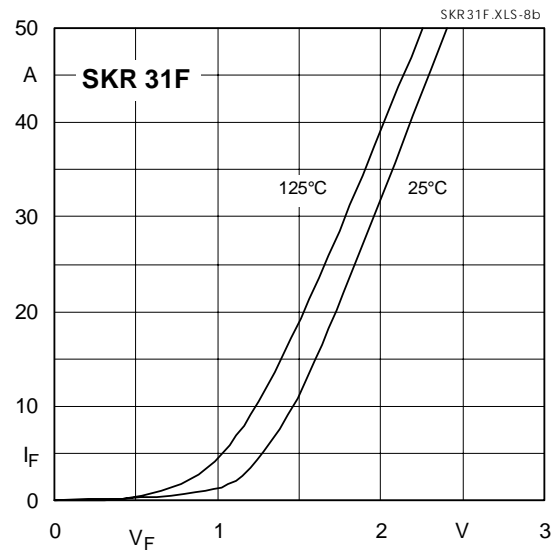


Fig. 8 b Typ. forward characteristics

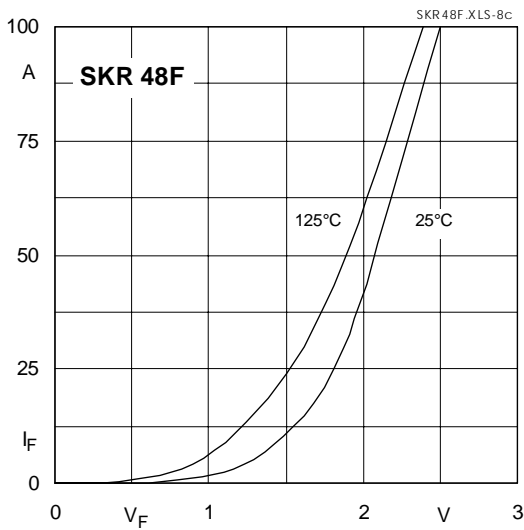


Fig. 8 c Typ. forward characteristics

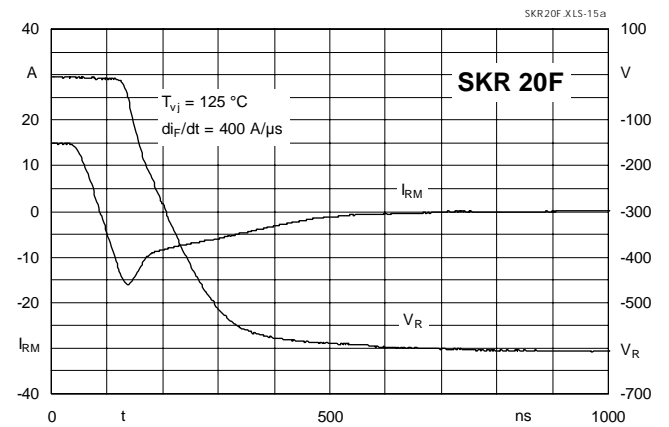


Fig. 15 a Typ. reverse recovery characteristics

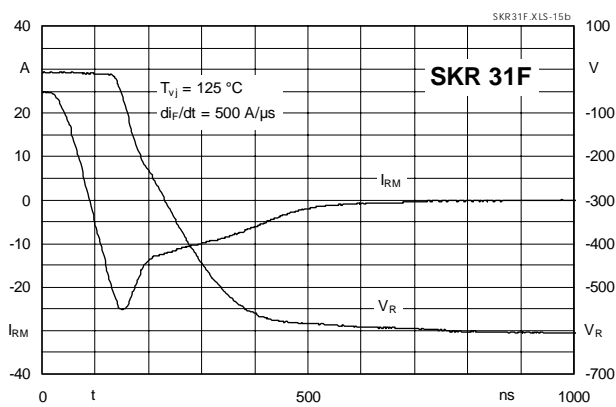


Fig. 15 b Typ. reverse recovery characteristics

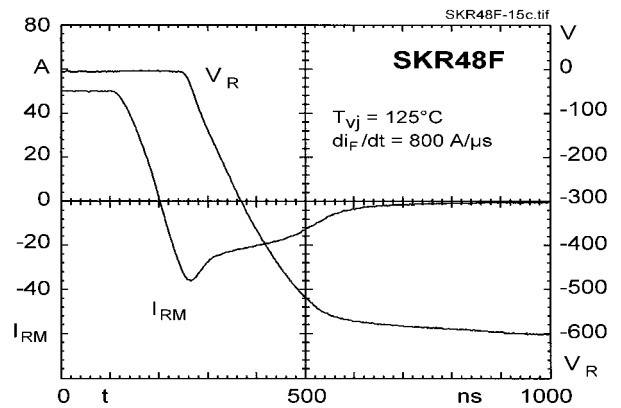
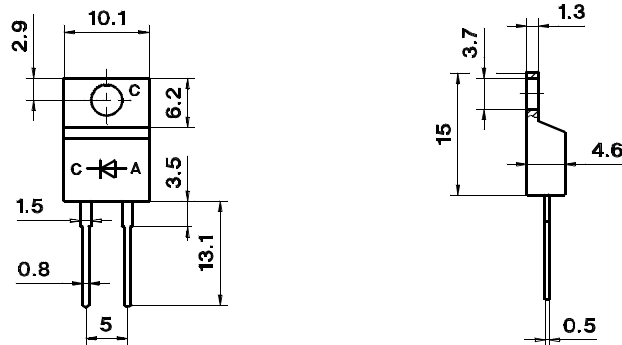


Fig. 15 c Typ. reverse recovery characteristics

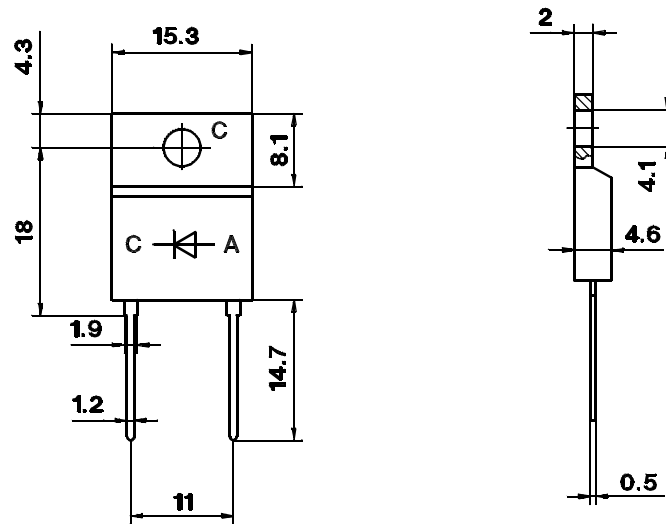
**SKR 20 F**

Case E 39  
TO-220 AC



**SKR 31 F**  
**SKR 48 F**

Case E 40  
TO-218



Dimensions in mm